

July 2009

FOD814 Series, FOD817 Series 4-Pin High Operating Temperature Phototransistor Optocouplers

Features

- AC input response (FOD814 only)
- Applicable to Pb-free IR reflow soldering
- Compact 4-pin package
- Current transfer ratio in selected groups:

FOD814: 20–300% FOD814A: 50–150% FOD817A: 80–160% FOD817B: 130–260% FOD817C: 200–400% FOD817D: 300–600%

- C-UL, UL and VDE approved
- High input-output isolation voltage of 5000Vrms
- Minimum BV_{CEO} of 70V guaranteed
- Higher operating temperatures (versus H11AXXX counterparts)

Applications

FOD814 Series

- AC line monitor
- Unknown polarity DC sensor
- Telephone line interface

FOD817 Series

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

FOB12

Description

The FOD814 consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a

silicon phototransistor output in a 4-pin dual in-line

package. The FOD817 Series consists of a gallium

arsenide infrared emitting diode driving a silicon

phototransistor in a 4-pin dual in-line package.

Absolute Maximum Ratings (T_A = 25°C Unless otherwise specified.)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

			Va	alue	Units
Symbol	Parameter		FOD814	FOD817	
TOTAL DEVIC	E			-1	
T _{STG}	Storage Temperature		-55 t	o +150	°C
T _{OPR}	Operating Temperature		-55 to +105	-55 to +110	°C
T _{SOL}	Lead Solder Temperature		260 fc	or 10 sec	°C
TJ	Junction Temperature		125	i Max.	°C
θ_{JC}	Junction-to-Case Thermal Res	istance	2	210	°C/W
P _{TOT}	Total Power Dissipation		2	200	mW
EMITTER					
١ _F	Continuous Forward Current		±50	50	mA
V _R	Reverse Voltage			6	
PD	Power Dissipation			70	
	Derate above 100°C			1.7	
DETECTOR					
V _{CEO}	Collector-Emitter Voltage			70	V
V _{ECO} Emitter-Collector Voltage				6	V
۱ _C	I _C Continuous Collector Current			50	mA
P _C	Collector Power Dissipation		1	150	mW
	Derate above 90°C		:	2.9	mW/°C

Electrical Characteristics (T_A = 25°C Unless otherwise specified.)

Individual Component Characteristics

Symbol	Parameter	Device	Test Conditions	Min.	Тур.*	Max.	Unit
EMITTER		Į				1	
V _F	Forward Voltage	FOD814	$I_F = \pm 20 \text{mA}$		1.2	1.4	V
		FOD817	I _F = 20mA		1.2	1.4	
I _R	Reverse Leakage Current	FOD817	V _R = 4.0V			10	μA
Ct	Terminal Capacitance	FOD814	V = 0, f = 1 kHz		50	250	pF
		FOD817	V = 0, f = 1kHz		30	250	
DETECTO	3						
I _{CEO}	Collector Dark Current	FOD814	$V_{CE} = 20V, I_F = 0$			100	nA
		FOD817	$V_{CE} = 20V, I_F = 0$			100	
BV _{CEO}	Collector-Emitter Breakdown	FOD814	I _C = 0.1mA, I _F = 0	70			V
	Voltage	FOD817	$I_{\rm C} = 0.1 {\rm mA}, I_{\rm F} = 0$	70			
BV _{ECO}	Emitter-Collector Breakdown	FOD814	I _E = 10μA, I _F = 0	6			V
	Voltage	FOD817	$I_{E} = 10 \mu A, I_{F} = 0$	6			

DC Transfer Characteristics

Symbol	DC Characteristic	Device	Test Conditions	Min.	Тур.*	Max.	Unit
CTR	Current Transfer	FOD814	$I_{F} = \pm 1 \text{mA}, V_{CE} = 5V^{(1)}$	20		300	%
	Ratio	FOD814A		50		150	
		FOD817	$I_{F} = 5mA, V_{CE} = 5V^{(1)}$	50		600	
		FOD817A		80		160	
		FOD817B		130		260	
		FOD817C		200		400	
		FOD817D		300		600	
V _{CE (sat)}	Collector-Emitter	FOD814	$I_F = \pm 20$ mA, $I_C = 1$ mA		0.1	0.2	V
	Saturation Voltage	FOD817	$I_F = 20mA, I_C = 1mA$		0.1	0.2	

AC Transfer Characteristics

Symbol	AC Characteristic	Device	Test Conditions	Min.	Тур.*	Max.	Unit
f _C	Cut-Off Frequency	FOD814	$V_{CE} = 5V$, $I_C = 2mA$, $R_L = 100\Omega$, -3dB	15	80		kHz
t _r	Response Time (Rise)	FOD814, FOD817	$V_{CE} = 2 \text{ V}, \text{ I}_{C} = 2\text{mA}, \text{ R}_{L} = 100\Omega^{(2)}$		4	18	μs
t _f	Response Time (Fall)	FOD814, FOD817			3	18	μs

*Typical values at $T_A = 25^{\circ}C$

Electrical Characteristics ($T_A = 25^{\circ}C$ Unless otherwise specified.) (Continued)

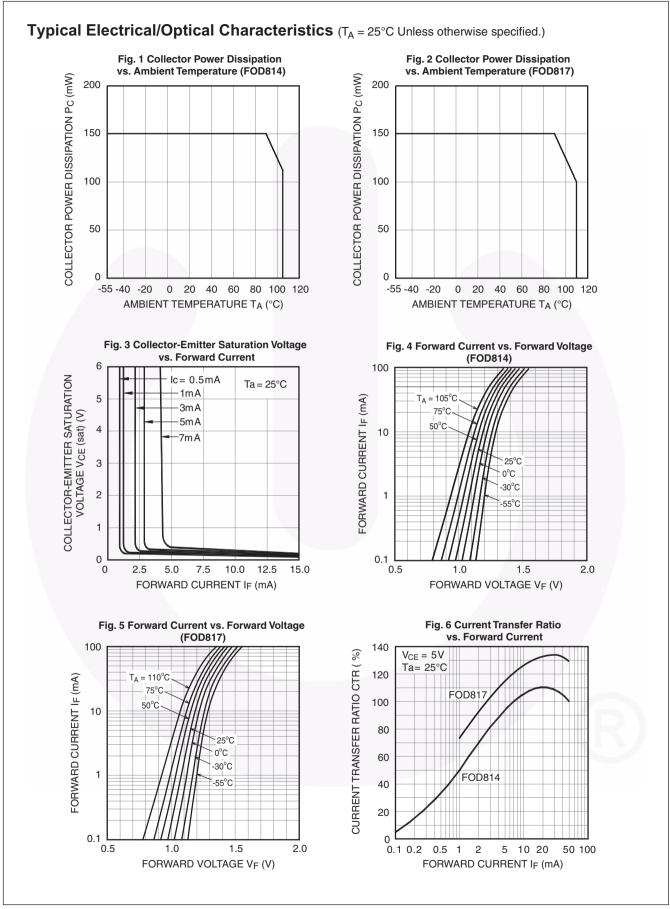
Isolation Characteristics

Symbol	Characteristic	Device	Test Conditions	Min.	Тур.*	Max.	Units
V _{ISO}	Input-Output Isolation Voltage ⁽³⁾	FOD814, FOD817	$ f = 60Hz, t = 1 min, \\ I_{I-O} \le 2\mu A $	5000			Vac(rms)
R _{ISO}	Isolation Resistance	FOD814, FOD817	V _{I-O} = 500VDC	5x10 ¹⁰	1x10 ¹¹		Ω
C _{ISO}	Isolation Capacitance	FOD814, FOD817	V _{I-O} = 0, f = 1 MHz		0.6	1.0	pf

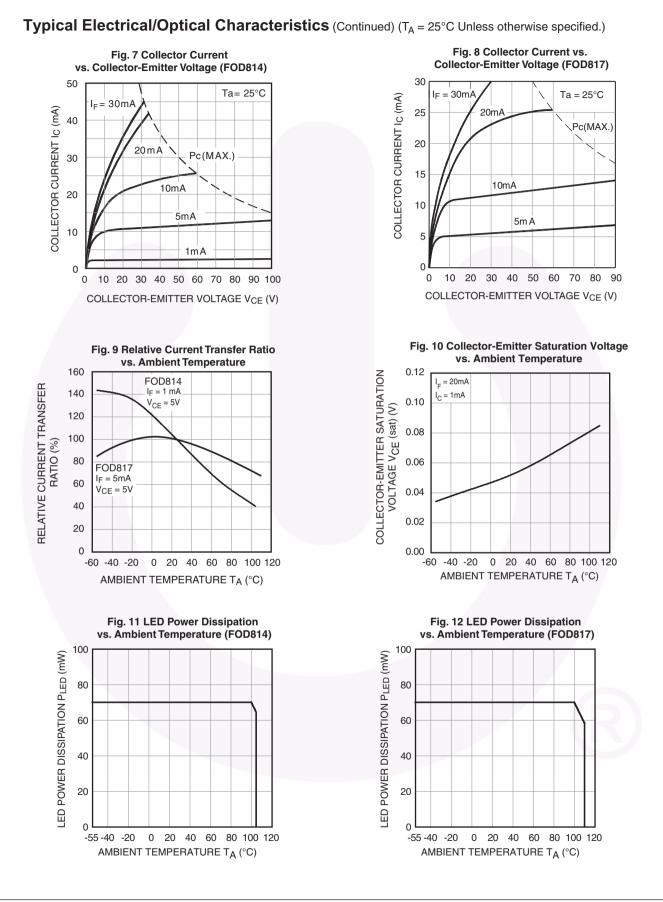
*Typical values at $T_A = 25^{\circ}C$

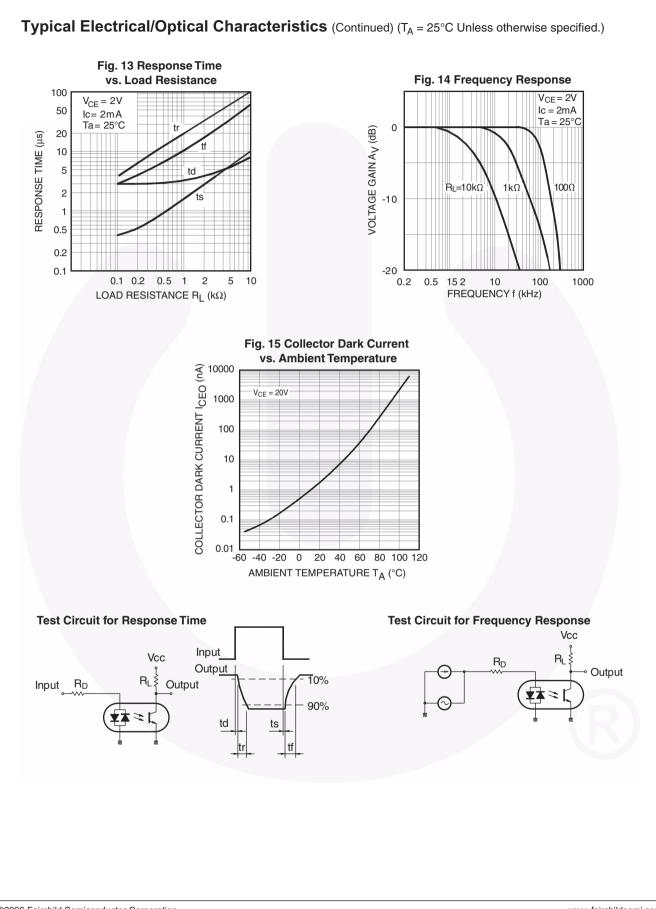
Notes:

- 1. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.
- 2. For test circuit setup and waveforms, refer to page 7.
- 3. For this test, Pins 1 and 2 are common, and Pins 3 and 4 are common.

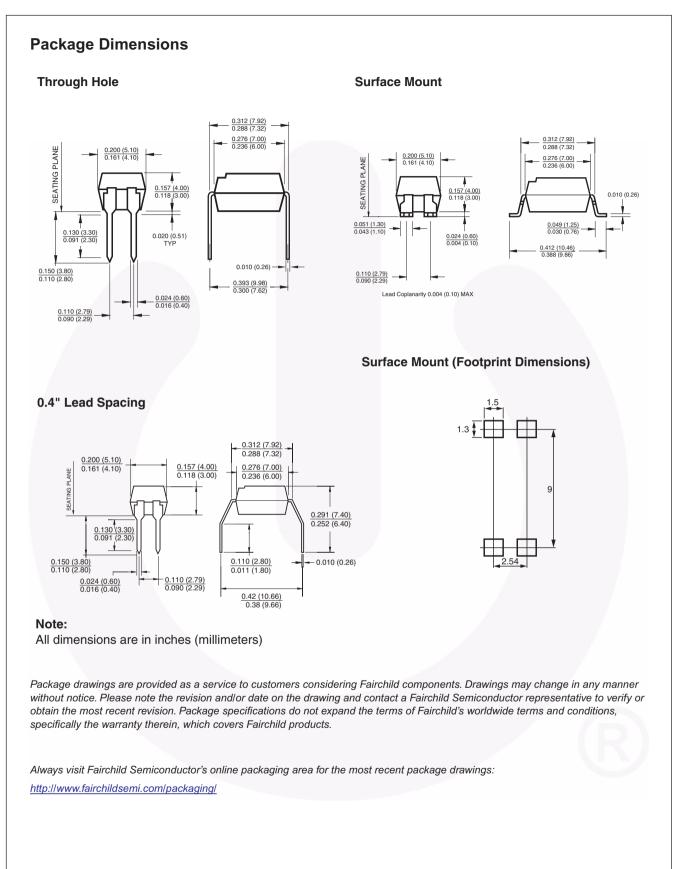


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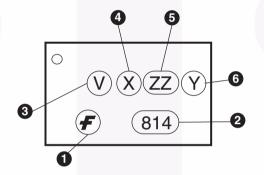


Definiti	Definitions					
1	Fairchild logo					
2	Device number					
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)					
4	One digit year code					
5	Two digit work week ranging from '01' to '53'					
6	Assembly package code					

Ordering Information

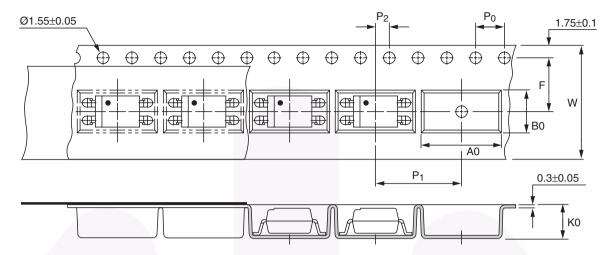
Option	Part Number Example	Description
S	FOD814S	Surface Mount Lead Bend
SD	FOD814SD	Surface Mount; Tape and reel
300	FOD814300	VDE Approved
300W	FOD814300W	VDE Approved, 0.4" Lead Spacing
3S	FOD8143S	VDE Approved, Surface Mount
3SD	FOD8143SD	VDE Approved, Surface Mount, Tape & Reel

Marking Information



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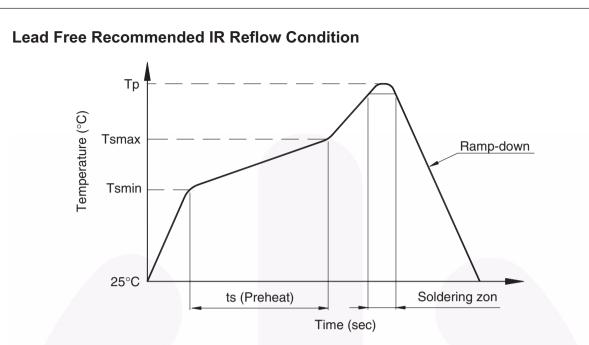
Carrier Tape Specifications



Note:

All dimensions are in millimeters.

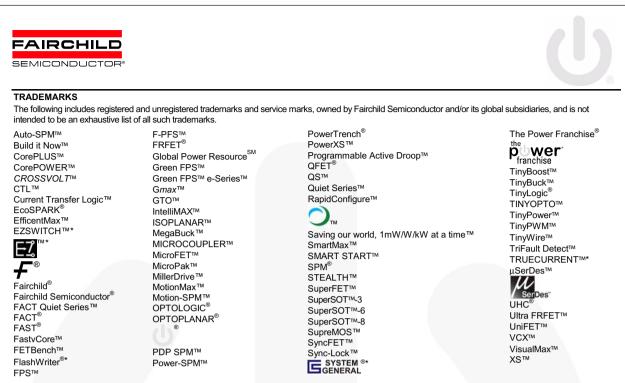
Symbol	Description	Dimensions in mm (inches)
W	Tape wide	16 ± 0.3 (.63)
P ₀	Pitch of sprocket holes	4 ± 0.1 (.15)
F P ₂	Distance of compartment	7.5 ± 0.1 (.295) 2 ± 0.1 (.079)
P ₁	Distance of compartment to compartment	12 ± 0.1 (.472)
A0	Compartment	10.45 ± 0.1 (.411)
B0		5.30 ± 0.1 (.209)
K0		4.25 ± 0.1 (.167)



Profile Feature	Pb-Sn solder assembly	Lead Free assembly
Preheat condition (Tsmin-Tsmax / ts)	100°C ~ 150°C 60 ~ 120 sec	150°C ~ 200°C 60 ~120 sec
Melt soldering zone	183°C 60 ~ 120 sec	217°C 30 ~ 90 sec
Peak temperature (Tp)	240 +0/-5°C	260 +0/-5°C
Ramp-down rate	6°C/sec max.	6°C/sec max.

Recommended Wave Soldering condition

Profile Feature	For all solder assembly
Peak temperature (Tp)	Max 260°C for 10 sec



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